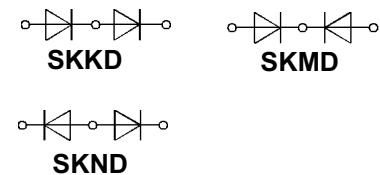
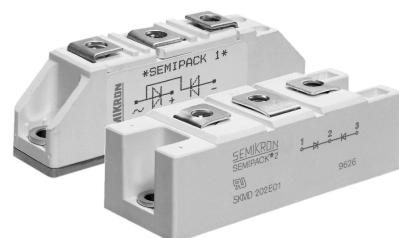


V_{RSM}	I_{FRMS} (maximum value for continuous operation)			
V_{RRM}	110 A		325 A	
V	I_{FAV} (sin. 180; $T_{case} = 85^\circ C$; 50 Hz)			
	48,5 A		207 A	
100	SKKD 50 E 01	SKND 50 E 01	SKMD 202 E 01	SKND 202 E 01
200	SKKD 50 F 02	SKND 50 E 02	SKMD 202 E 02	SKND 202 E 02
300	SKKD 50 E 03	SKND 50 E 03	SKMD 202 E 03	SKND 202 E 03
400	SKKD 50 E 04	SKND 50 E 04	-	-

Ultrafast Epitaxial Diode Modules

SEMIPACK® 1
SKKD 50 E SKND 50 E

SEMIPACK® 2
SKMD 202 E SKND 202 E



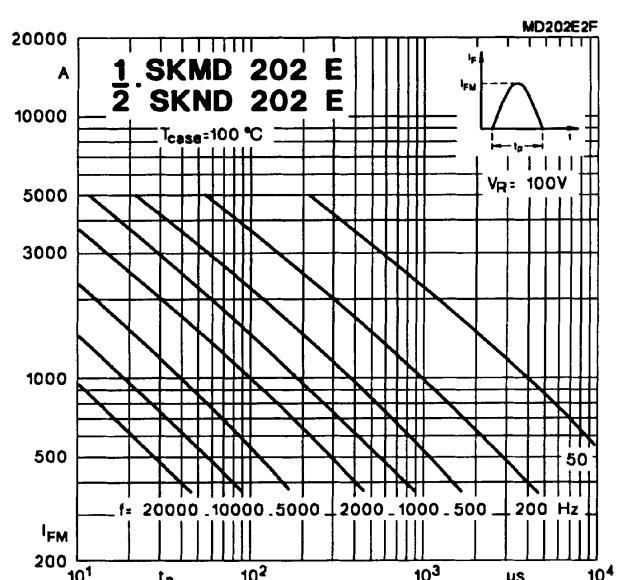
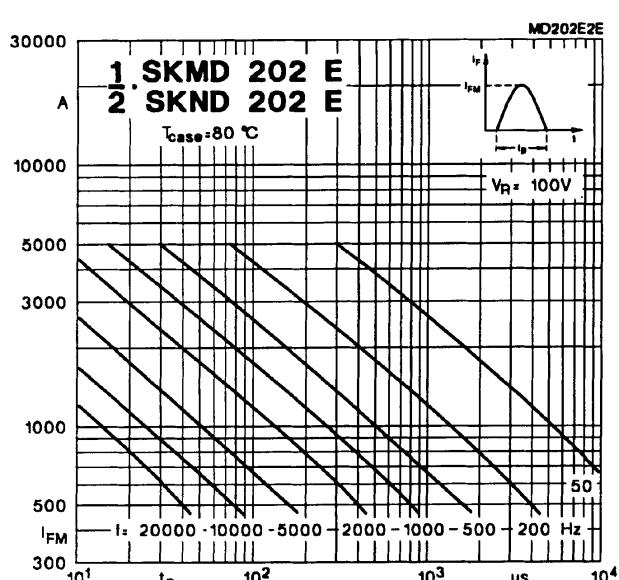
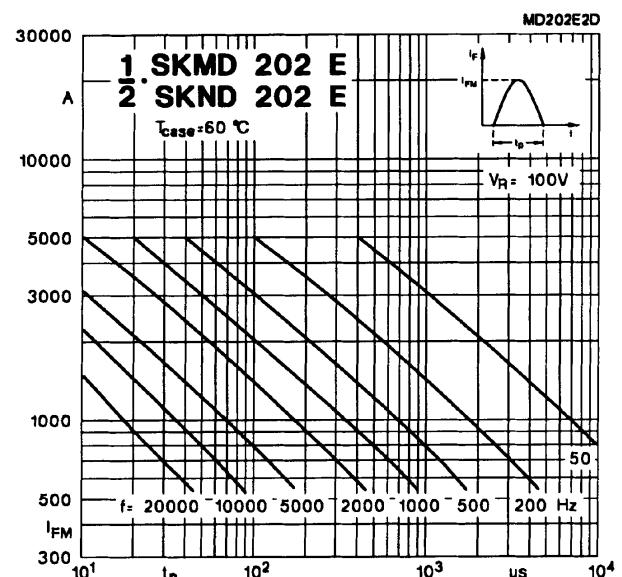
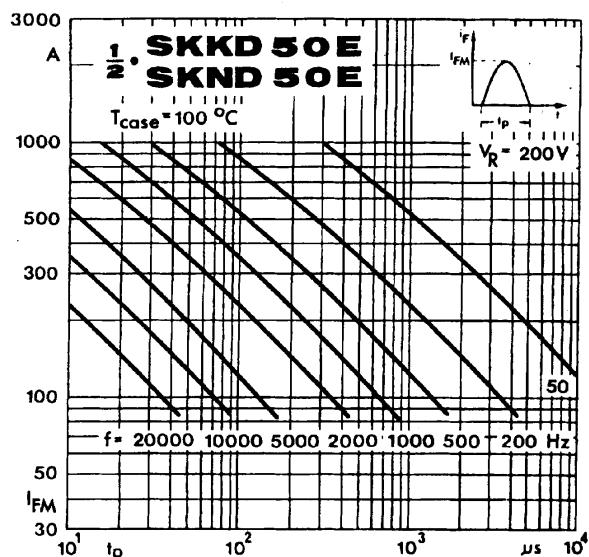
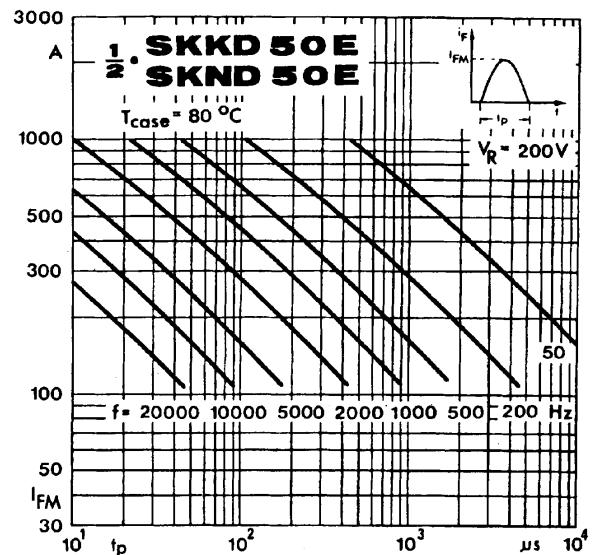
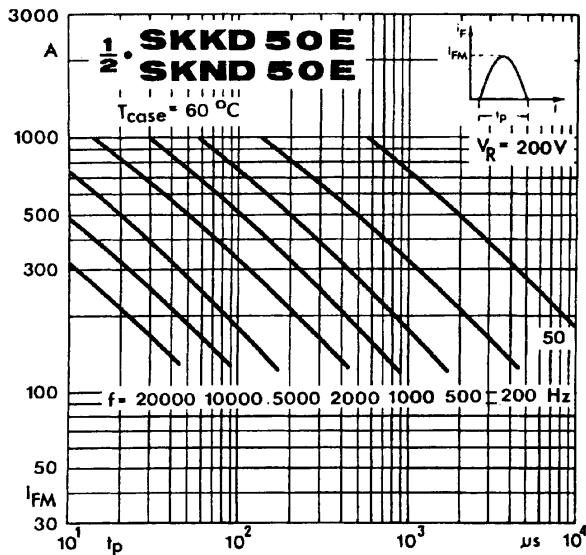
Symbol	Conditions	SKKD 50 E SKND 50 E	SKMD 202 E SKND 202 E	Units
I_{FAV}	sin. 180; $T_{case} = 85^\circ C$	48,5	207	A
I_{FSM}	$T_{vj} = 25^\circ C$ $T_{vj} = 150^\circ C$	800 700	3 200 2 800	A A
i^2t	$T_{vj} = 25^\circ C$ $T_{vj} = 150^\circ C$	3 200 2 450	51 000 39 000	A^2s A^2s
t_{rr}	$T_{vj} = 25^\circ C$; $I_F = 1 A$; $-di_F/dt = 15 A/\mu s$; $V_R = 30 V$, $I_{rr} = 0,25 I_{RM}$	60	140	ns
Q_{rr}	$\left. \begin{array}{l} T_{vj} = 150^\circ C; I_F = 50 A; \\ -di_F/dt = 100 A/\mu s; \end{array} \right\} V_R = 100 V$	0,7 10	2 16	μC A
I_{RM}	$T_{vj} = 25^\circ C$; $V_R = V_{RRM}$	0,2	2	mA
I_R	$T_{vj} = 130^\circ C$; $V_R = V_{RRM}$	40	100	mA
V_F	$T_{vj} = 25^\circ C$; ($I_F = \dots$); max.	1,6 (120 A)	1,65 (500 A)	V
$V_{(TO)}$	$T_{vj} = 150^\circ C$	0,8	0,8	V
r_T	$T_{vj} = 150^\circ C$	6,5	1,5	$m\Omega$
R_{thjc}	per diode / per module	0,85 / 0,43	0,2 / 0,1	$^\circ C/W$
R_{thch}	per diode / per module	0,2 / 0,1	0,1 / 0,05	$^\circ C/W$
T_{vj}		$-40 \dots +150$		$^\circ C$
T_{stg}		$-40 \dots +125$		$^\circ C$
V_{isol}	a. c. 50 Hz; r.m.s.; 1 s/1 min	3000 / 2500		V~
M_1	to heatsink	5 (44 lb. in.) $\pm 15\%$		Nm
M_2	to terminals	3 (26 lb. in.) $\pm 15\%$		Nm
w	approx.	120	250	g
Case	SKKD SKMD SKND	A 20 A — A 19	— A 51 A 52	

Features

- Isolated metal baseplate
- Very short recovery times
- Low switching losses
- Up to 400 V peak inverse voltage
- **SKKD** half bridge or centre tap connections:
SKMD common cathode
SKND common anode
- UL recognized, file no. E 63 532

Typical Applications

- Switched mode power converters
- Invers diode for transistors in AC and DC motor controls
- Uninterruptible power supplies (UPS)



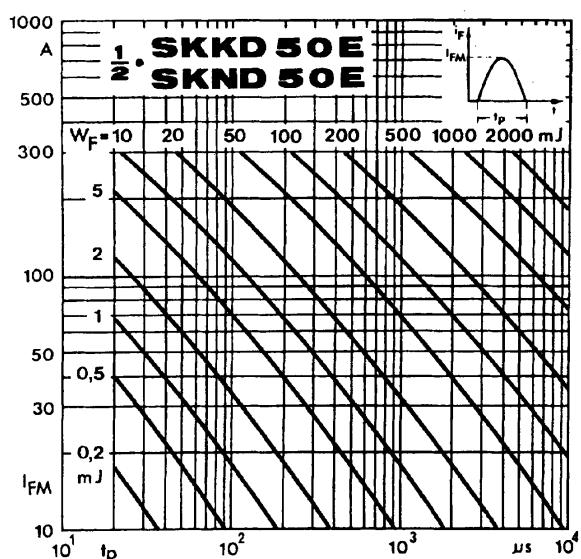


Fig. 13 a Forward energy dissipation, sinusoidal

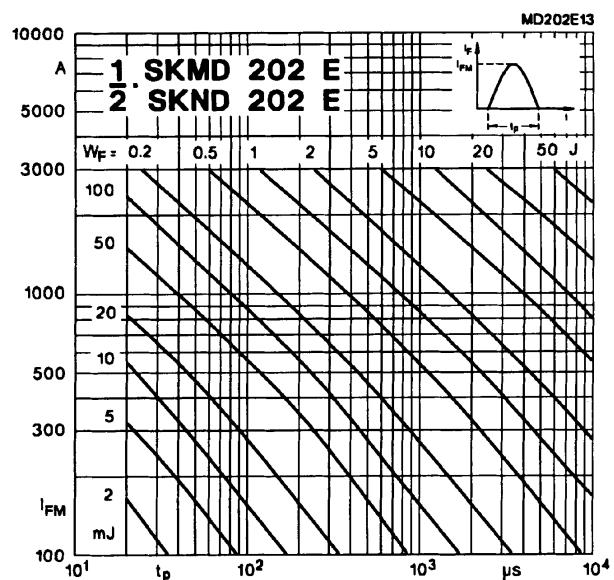


Fig. 13 b Forward energy dissipation, sinusoidal

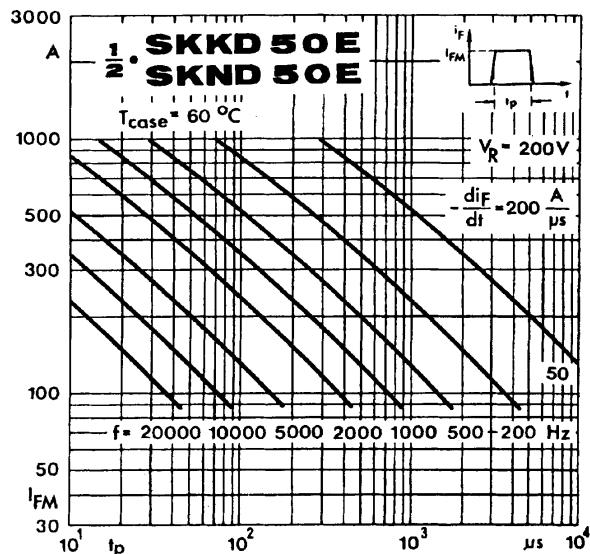


Fig. 14 a Rated rectangular peak forward current

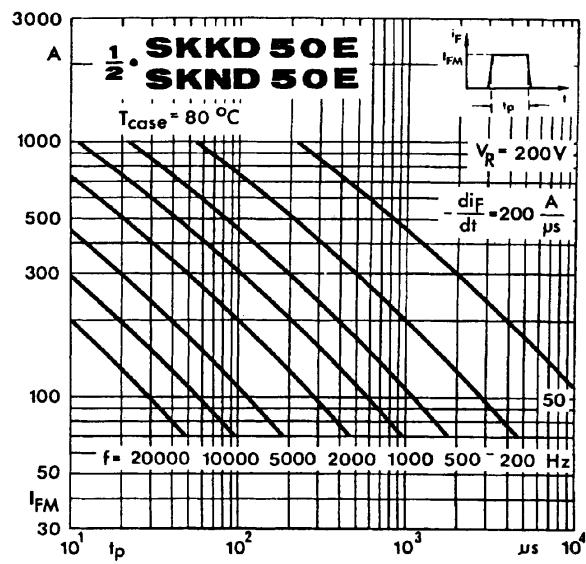


Fig. 14 b Rated rectangular peak forward current

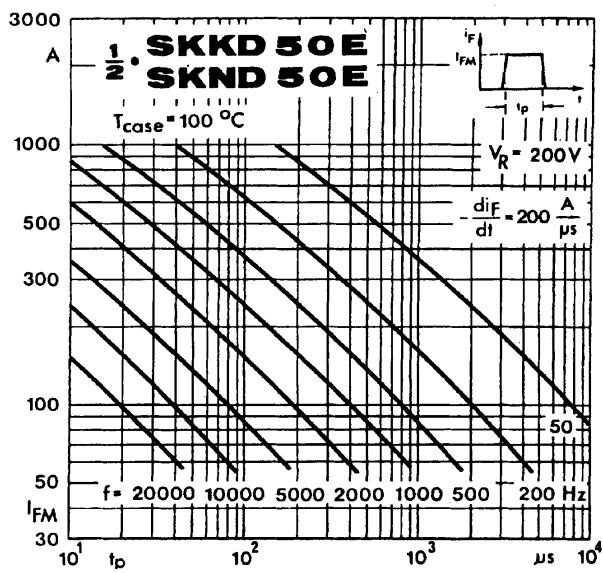


Fig. 14 c Rated rectangular peak forward current

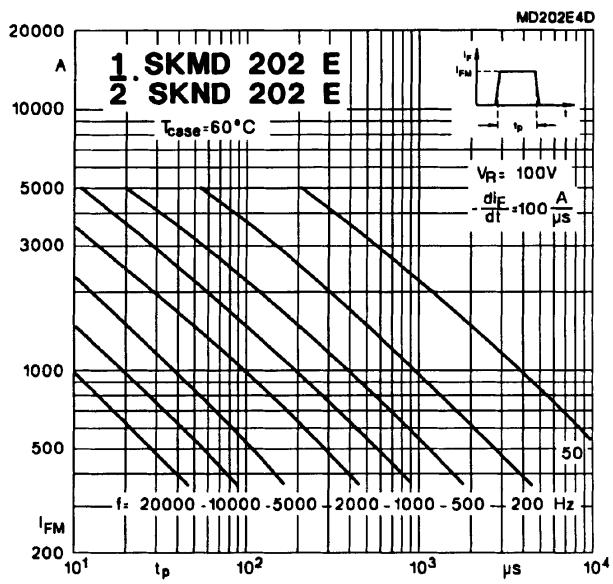


Fig. 14 d Rated rectangular peak forward current

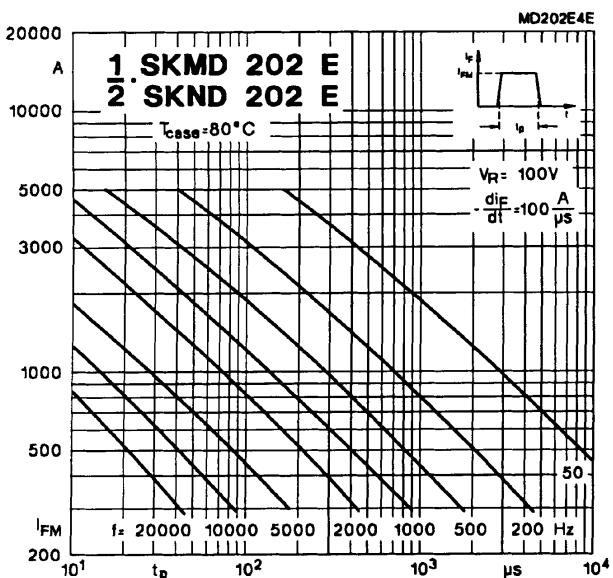


Fig. 14 e Rated rectangular peak forward current

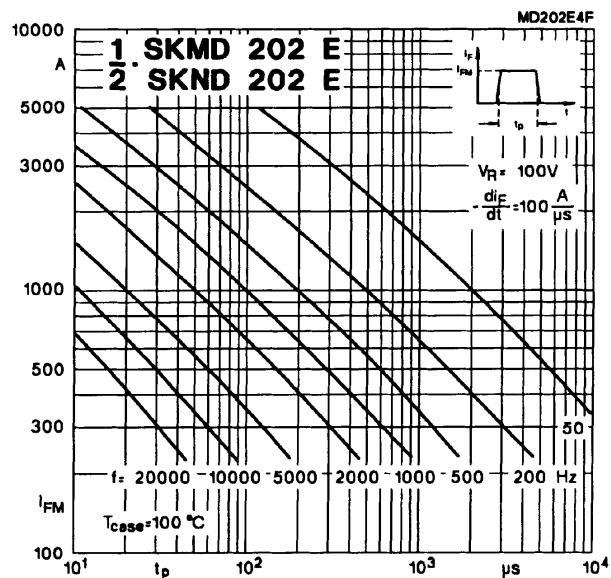


Fig. 14 f Rated rectangular peak forward current

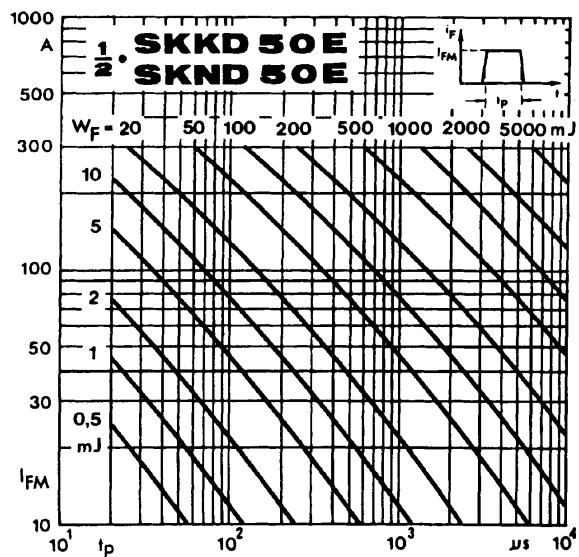


Fig. 15 a Forward energy dissipation, rectangular

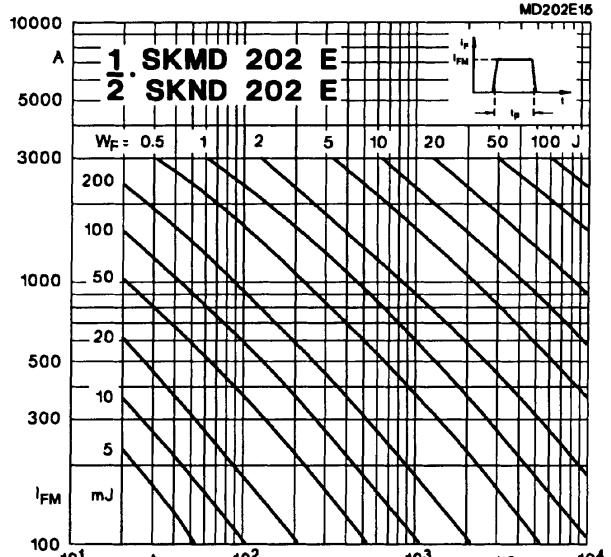


Fig. 15 b Forward energy dissipation, rectangular

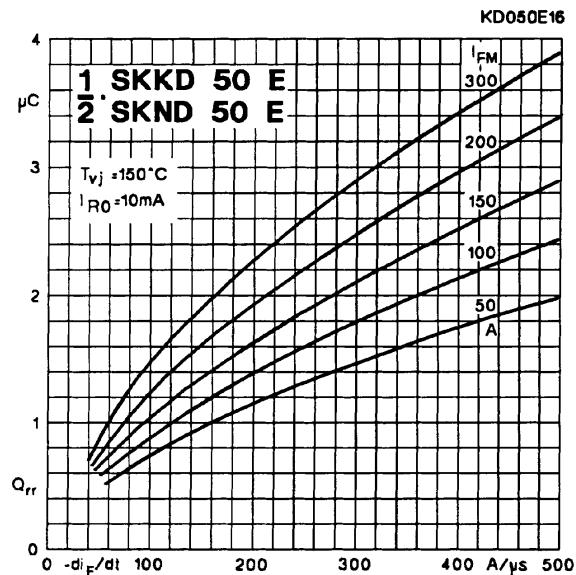


Fig. 16 a Recovered charge vs. current decrease

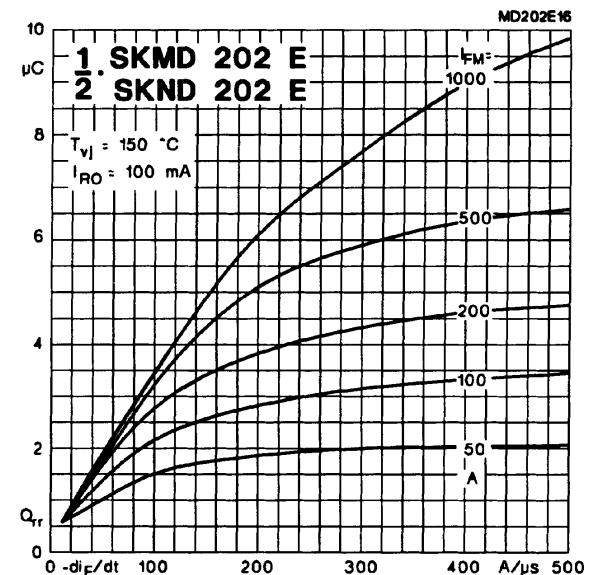


Fig. 16 b Recovered charge vs. current decrease

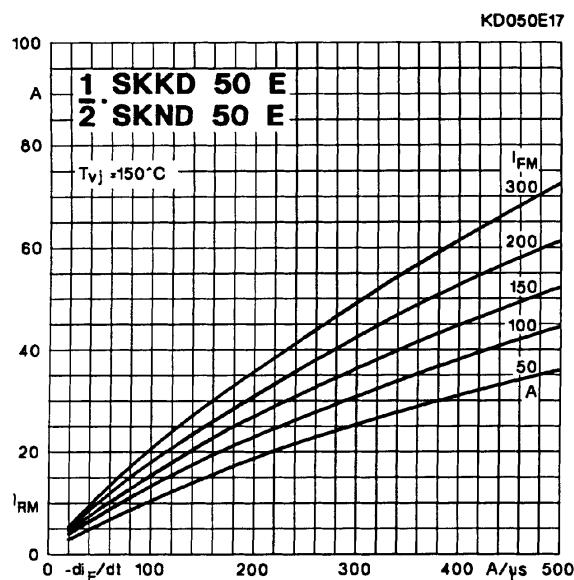


Fig. 17 a Peak recovery current vs. current decrease

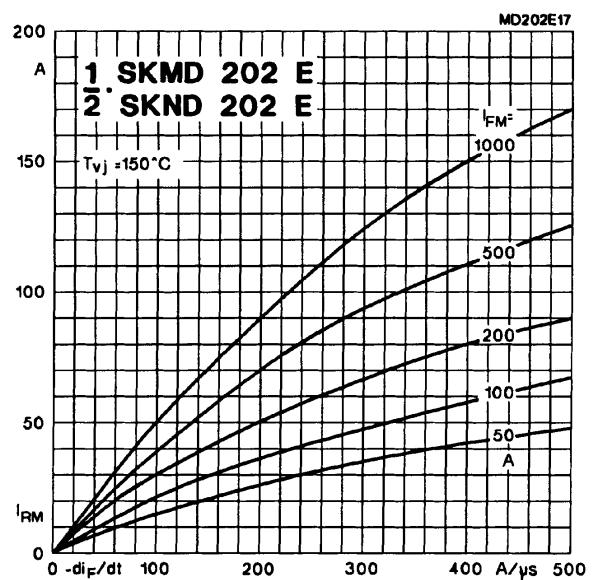


Fig. 17 b Peak recovery current vs. current decrease

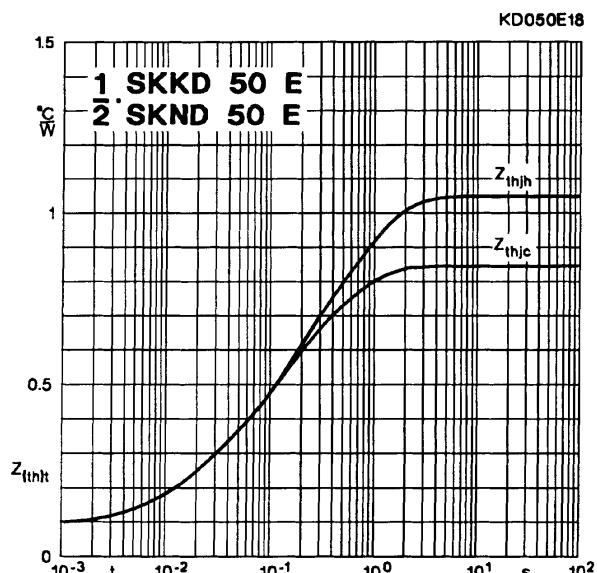


Fig. 18 a Transient thermal impedance vs. time

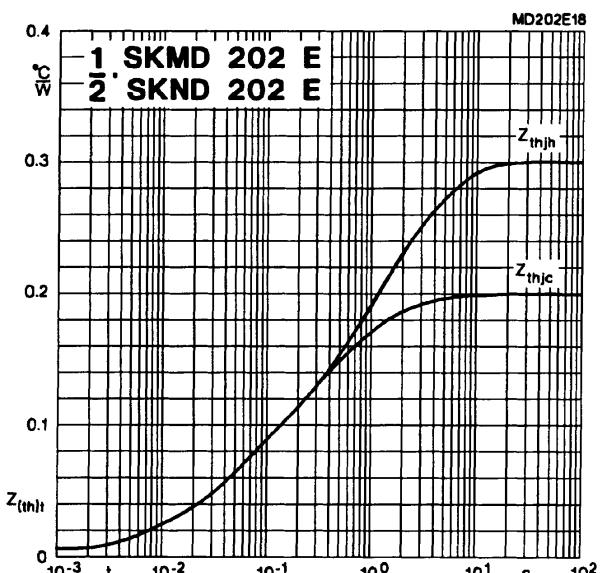


Fig. 18 b Transient thermal impedance vs. time

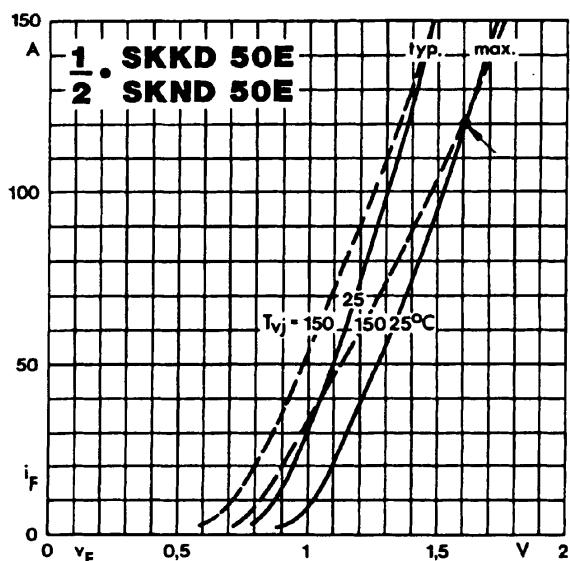


Fig. 19 a Forward characteristics

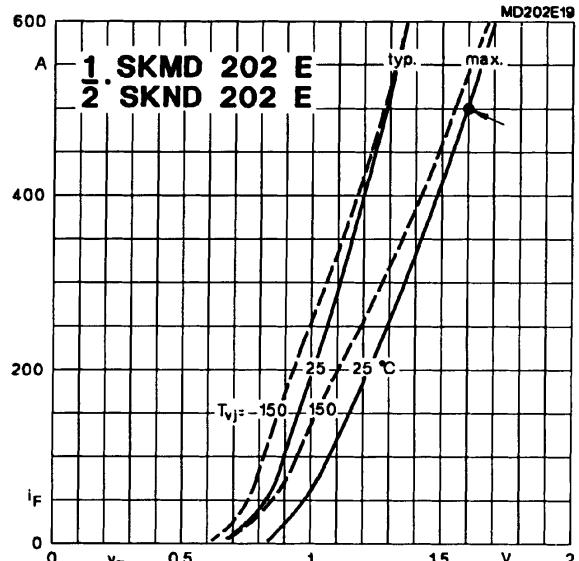


Fig. 19 b Forward characteristics

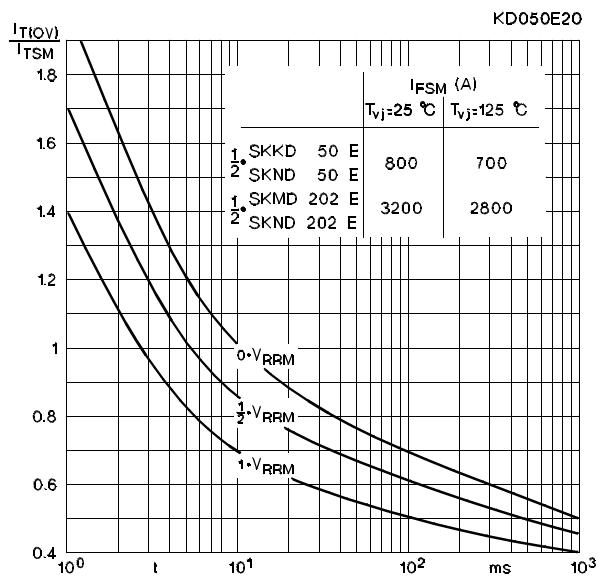
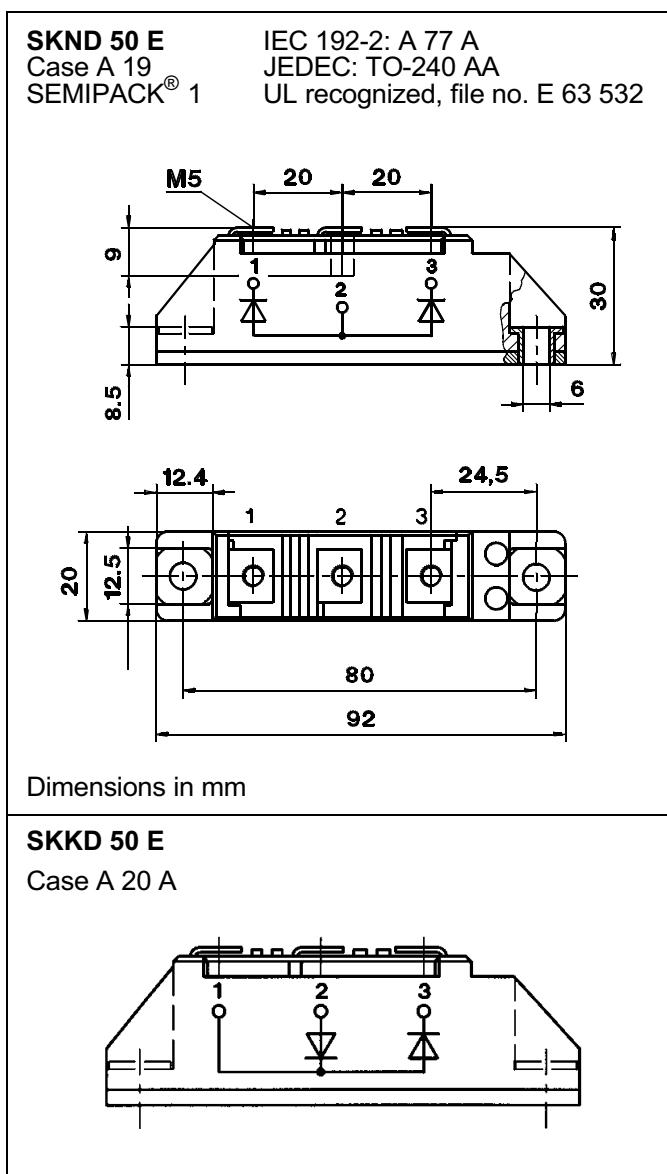


Fig. 20 Surge overload current vs. time



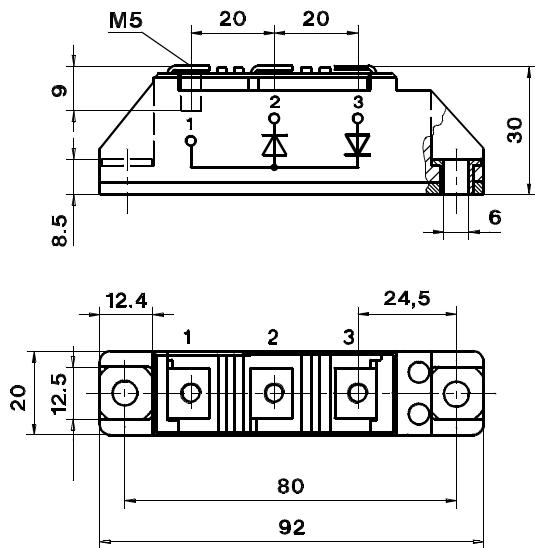
SKKD 105 F, 115 F

Case A 10

IEC 192-2: A 77 A
JEDEC: TO-240 AA

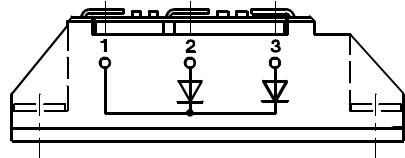
SEMIPACK® 1

UL recognized, file no. E 63 532



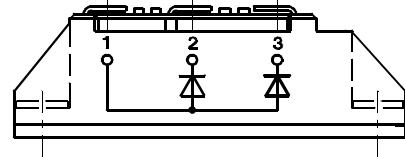
SKMD 105 F

Case A 33



SKND 105 F

Case A 37



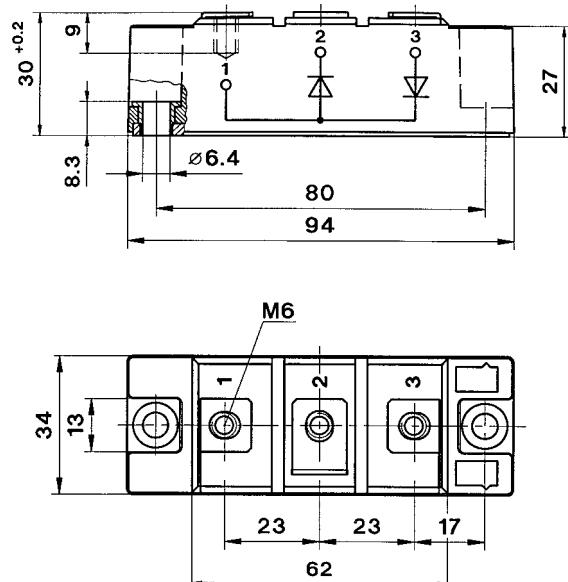
Dimensions in mm

SKKD 60 F, 75 F

Case A 23

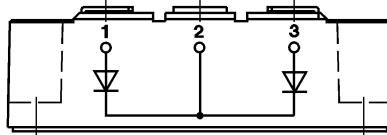
SEMIPACK® 2

UL recognized, file no. E 63 532



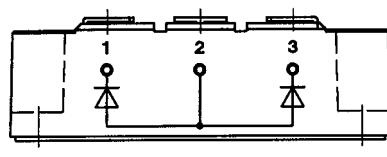
SKMD 150 F, 202 E

Case A 51



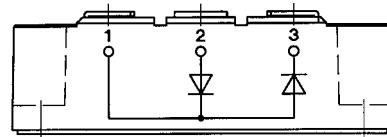
SKND 150 F, 202 E

Case A 52



SKKD 150 F, 170 F

Case A 53



Dimensions in mm